SURFACE RESISTANCE RF MEASUREMENTS OF MATERIALS USED FOR ACCELERATOR VACUUM CHAMBERS

Philippe Goudket^{1,3}, Lewis Gurran^{1,2}, Graeme Burt², Mark Roper^{1,3}, Stuart Wilde^{1,4}, Oleg B. Malyshev^{1,3}, Reza Valizadeh^{1,3} ¹ASTeC, STFC, Daresbury Laboratory, Daresbury, Warrington, Cheshire, UK ²Lancaster University, Cockcroft Institute, Lancaster, UK ³Cockcroft Institute, Warrington, Cheshire, UK ⁴Loughborough University, Loughborough, UK

Abstract

The RF surface resistance of accelerator vacuum chamber walls can have a significant impact on the beam quality. There is a need to know how the use of a new material, surface coating or surface treatment can affect the RF surface resistance. ASTeC and Lancaster University have designed and built two test cavities where one face can be replaced with a sample in the form of a flat plate. The measurements are performed with a network analyser at the resonant frequency of approximately 7.8 GHz.

INTRODUCTION

If one considers the formulation of the unloaded quality factor Q_0 of an RF cavity [1] one can write

$$Q_0 = \frac{2\pi f_0 \mu_0 \iiint_V |H|^2 . dV}{\iint_S R_S |H|^2 . dS}$$
(1)

where *H* is the magnetic field, R_S is the surface resistance of the cavity walls and f_0 is the resonant angular frequency of the cavity. To accommodate the possibility of a cavity being comprised of two parts (a cavity and a sample) which could be made of different metals or otherwise have different R_S values, one can most conveniently rewrite this as

$$Q_0 = \frac{G}{R_S^{sample} p_S + R_S^{cavity} p_C}$$
(2)

where G is the geometry constant of the cavity [1], defined as

$$G = \frac{2\pi f_0 \mu_0 \iiint_V |H|^2 . dV}{\iint_S |H|^2 . dS}$$
(3)

 R_s^{sample} and R_s^{cavity} are the surface resistance of the sample and the cavity respectively, and p_s and p_c the sample and cavity ratios – the proportion of the total field dissipated over their respective surfaces, i.e.

$$p_S = \frac{\iint_{sample} |\mathbf{H}|^2 . ds}{\iint_S |\mathbf{H}|^2 . ds} \tag{4}$$

$$p_{C} = \frac{\iint_{cavity} |H|^{2} ds}{\iint_{S} |H|^{2} ds} = 1 - p_{S}$$
(5)

For any similarly-shaped cavity G and p_S are in principle constant, irrespective of the materials used.

This implies that, knowing R_S^{cavity} , G and p_S for a given cavity we can calculate R_S for any sample by placing it on top of the cavity and finding the unloaded Q-factor of the resulting RF resonance.

$$R_{S}^{sample} = \frac{{}^{G}/{Q_{0}} - R_{S}^{cavity}(1-p_{S})}{p_{S}}$$
(6)

METHOD

Calculation of Q_0

Two double-choked pillbox-type cavities were used to take our measurements, one of which can be seen in Fig. 1. The choked cavity allows the testing of flat samples without the need for flanges and RF seals. Both cavities were manufactured to identical dimensions by Niowave Inc. [2], one being made from aluminium and one from niobium.



Figure 1: A two-choked 8 GHz Al test cavity.

In each case the samples, in the form of flat plates or discs of sufficient width to completely cover the outer choke, were placed on top of the cavity with spacers providing a gap of ~ 2 mm between the cavity and the sample. An axially-mounted coaxial antenna was attached to a calibrated network analyser to induce RF resonance, and the coefficient of signal reflection (S_{II}) measured against frequency. Initial setup required that the spacing between the sample and the cavity was adjusted to

7: Accelerator Technology

T06 - Room Temperature RF

WEPHA053

a maximise signal loss near the resonant frequency of the is first mode (approximately 7.8 GHz). The probe depth was adjusted to induce near-critical coupling, as judged from a Smith Chart of S_{II} . [3]

 Q_{0} , was calculated using the formula

$$Q_0 = \frac{f_0}{f_2 + f_3 - f_1 - f_4} \tag{7}$$

title of the work, where f_1 and f_2 are the frequencies at which the jimaginary components of S₁₁ are minimal and maximal For respectively with the system in the detuned open position. f_3 and f_4 are the frequencies at which the imaginary $\underline{\mathfrak{S}}$ component of S_{11} are ± 1 respectively in the detuned open g position. [3]

Calculatio Principles Calculation of Surface Resistance from First

The surface resistance R_s of a metal under AC stimulation depends on four factors; its bulk electrical resistivity ρ and magnetic permeability μ , the AC The surface resistance R_S of a metal under AC Ξ frequency f and its surface roughness. In the GHz regime \vec{E} all four are important contributors to R_S . For a perfectly $R_{S} = \sqrt{\pi \mu_{0} f \rho}$

$$R_S = \sqrt{\pi \mu_0 f \rho} \tag{8}$$

distribution to account for the effect of the finite skin depth in the metals under AC excitation [1].

Hammerstad and Bekkadal (1975) produced an empirical formula describing the effect of the RMS roughness, R_Q , on R_S . Based on their observations [4] an

$$R_{S} = \left(1 + \frac{2}{\pi} \tan^{-1} \left(1.4 \times R_{Q}^{2} \times \frac{\pi \mu f}{\rho}\right)\right) \tag{9}$$

additional factor applies as follows: $R_{S} = \left(1 + \frac{2}{\pi} \tan^{-1} \left(1.4 \times R_{Q}^{2} \times \frac{\pi \mu f}{\rho}\right)\right) \qquad (9)$ The sample surface roughness was calculated using in measurement data from an interferometric microscope by \succeq scanning the surfaces of five metal samples: metal discs \bigcup made of Cu, Al, Nb and 304 Stainless Steel and a ~5 μ me thick Cu film deposited via pulsed DC magnetron sputtering onto a Silicon (100) wafer. of 1

A theoretical value of $R_{\rm S}$ was then calculated for each sample using the modified formula (9) above.

Due to its physical dimensions the available interferometric microscope could not be used to obtain a roughness profile for the surface of the cavities themselves. As a consequence, only an upper limit was set $\frac{1}{2}$ themselves. As a consequence, only an upper mine was see so on their R_Q , and hence R_S , based on the manufacturer's B specifications.

ma Comparison of Measured and Theoretical work Results

from this The first step in an attempt to validate this method was to plot the calculated and measured values of $R_{\rm s}^{sample}$ for all samples against one another. The data from both cavities was observed to be in good agreement (coefficient of determination > 0.97) to a linear relationship. A manual iterative method was used to find the values of R_s^{cavity} , G and p_s for which the relationship most closely approximated y = x. As would be expected such values of G and p_S were the same for both cavities, at ~224 and ~0.37 respectively.

These figures were then used as the starting point for a more precise fitting technique, using MathCAD [5]. Here, for each value of p_s and R_s^{cavity} , R_s^{sample} was swept across a small range of values and the point at which both cavities returned the same value of G was logged. It was observed that the returned value of G was 225 for all sample-cavity combinations, to within the standard deviation of the measurements, when $p_s = 0.375$.

This matched very closely with values for G and p_S calculated from first principles using a CST [6] Microwave Studio simulation (shown in Fig. 2): G =224 and $p_{\rm S} = 0.375$.



Figure 2: Simulated distribution of the H-field on the sample (top) and cavity and chokes (bottom).

RESULTS AND DISCUSSION

Table 1 shows the calculated values of R_S at RF frequency f = 7.8 GHz.

Table 1: Calculated Values of R_S at 7.8 GHz

Sample	$a(\Omega m)$	P(m)	$R_{S}(\mathrm{m}\Omega)$
Sample	$p(s_{2111})$	$K_Q(m)$	calc
Cu plate	1.72×10 ⁻⁸ [7]	4.09×10 ⁻⁷	28.6
Al	2.73×10 ⁻⁸ [7]	4.05×10 ⁻⁷	34.0
304 SS	7.20×10 ⁻⁷ [8]	1.44×10 ⁻⁶	160
Nb	1.52×10^{-7} [7]	(1×10 ⁻⁶)	80.7
Cu film	1.72×10 ⁻⁸ [7]	9.08×10 ⁻⁶	22.7

Note that $\mu \approx \mu_0$ [7, 8] for all the materials we used. Table 2 shows the mean value of Q_0 for each cavitysample combination from sets of five consecutive calculations - removing, rotating and replacing the sample between each one.

The uncertainty comes from combining (as the root of the sum of the squares) the relative standard deviation within these sets of readings and the estimated relative error in the measurements of f_0 , f_1 , f_2 , f_3 and f_4 .

	~	
Sample	Q ₀ (Al cavity)	Q_0 (Nb cavity)
Cu plate	5398 (+ 0.77%)	3368 (+ 1.54%)
Al	4787 (+ 2.28%)	2981 (+ 4.16%)
304 SS	2382 (+ 1.98%)	1941 (+ 0.64%)
Nb	3957 (+ 1.27%)	2703 (+ 1.26%)
Cu film	5333 (+ 2.07%)	3324 (+ 1.98%)

Table 3 shows the resultant values of R_S^{sample} for each cavity-sample combination, as well as those calculated from first principles.

The calculations used some values which it was not possible to obtain from literature or determine from direct measurement:

- For both cavities a value of G = 255 and $p_S = 0.375$ were used, from the MathCAD best-fit solution (supported by the CST calculations)
- R_0 for the cavities was assumed to be that which gave the best y = x fit to the data.
- R_{0} for the Nb plate comes from the manufacturer's specifications.

Table 3: Comparison of the Values of R_S calculated from First Principles and from the Q_0 Readings for 7.8 GHz Al and Nb Cavities

Sample	R_{S} , calculated (Ω)	R_{S}^{sample} from Q_{0} , Al (Ω)	R_{S}^{sample} from Q_{0} , Nb (Ω)
Cu film	2.27 x 10 ⁻²	2.84 x 10 ⁻²	2.34 x 10 ⁻²
Cu plate	2.86 x 10 ⁻²	2.70 x 10 ⁻²	2.09 x 10 ⁻²
Al	3.36 x 10 ⁻²	3.85x10 ⁻²	4.43 x 10 ⁻²
304 SS	1.60 x 10 ⁻¹	1.68x10 ⁻¹	1.52 x 10 ⁻¹
Nb	8.06 x 10 ⁻²	6.75x10 ⁻²	6.49 x 10 ⁻²

Table 4: Comparison of the Values of p calculated from the Literature and from the Q₀ Readings for 7.8 GHz Excitation of the Al and Nb Cavities

Sample	ρ (Ω m)	$ ho$ from $Q_{\theta_{j}}$ Al (Ω m)	$ ho$ from Q_0 , Nb (Ω m)
Cu film	1.72×10 ⁻⁸ [7]	2.61×10 ⁻⁸	1.77×10 ⁻⁸
Cu plate	1.72×10 ⁻⁸ [7]	2.36×10 ⁻⁸	1.42×10 ⁻⁸
Al	2.73×10 ⁻⁸ [7]	4.79×10 ⁻⁸	6.35×10 ⁻⁸
304 SS	7.20×10 ⁻⁷ [8]	9.13×10 ⁻⁷	7.49×10 ⁻⁷
Nb	1.52×10 ⁻⁷ [7]	1.47×10 ⁻⁷	1.36×10 ⁻⁷

7: Accelerator Technology

T06 - Room Temperature RF

The results suggest that this is have here a useful and robust method for determining R_s^{sample} . The internal publisher, consistency of our results suggests that its effect on Q_0 is as is expected, and that G, p_S and p_C can be accurately calculated for a cavity of this sort using CST Microwave work, Studio. The empirical formula for the surface resistance of a rough surface means that we can either calculate R_c^{cavity} from first principles or, if measuring the cavity R_O title of is not practical, find a good estimate for it via the best fit to the data from several 'calibration' samples. Therefore, author(s), once we measure Q_0 on that cavity for each subsequent unknown sample we have all the components we need to calculate R_s^{sample} attribution to the

Possible sources of systematic error include:

- The assumption that the metal remains in the normal skin-depth regime.
- The roughness-modified formula for R_S is only an approximation.
- The fact that the samples we used might have a different bulk resistivity to that given by the literature.
- Surface oxidation, dirt, and/or fractures beneath the surface of the sample could all also have had an effect on R_S which is not currently quantifiable. Coupling losses cannot be accounted for.

The cavity was originally designed to measure R_{c}^{sample} at cryogenic temperatures [9]. If the bandwidth permits, we will try to duplicate the measurements using the method described above, but we plan to use calorimetric methods which will afford a far more reliable method of measuring the much-higher Qfactors. Additional considerations, and details of the apparatus, are covered in another paper [9].

CONCLUSION

The method of measuring RF surface resistance using two-choke test cavities at room temperature was analytically developed and implemented in two cavities BΥ made of Al and Nb. Measured values of $R_{\rm S}$ for Cu, Al, Nb 8 and 304 stainless steel are in a good agreement with theoretically calculated values.

REFERENCES

- [1] H. Padamsee, J. Knobloch and T. Hayes, RF Superconductivity for Accelerators, Wiley, 1998 pp. 45, 78-79.
- [2] NIOWAVE Inc., 1012 N Walnut St, Lansing, MI 48906.
- [3] F. Caspers 2012, RF Engineering Basic Concepts: The Smith Chart http://arxiv.org/pdf/1201.4068.pdf 19 Jan 2012.
- [4] E. O. Hammerstad and F. Bekkadal, A Microstrip Handbook, ELAB Report, STF 44 A74169, University of Trondheim, Norway, 1975, pp 98-110. 101", Cited in "Microwaves 26/01/15: http://www.microwaves101.com/encyclopedias/surfa ce-roughness

naintain

must

distribution of this work

<u>5</u>.

icence (© 201

3.0

under the terms of the

be used

work

from this

- [5] MathCAD, PTC, 140 Kendrick Street, Needham MA 02494, USA.
- [6] CST AG, Bad Nauheimer Str. 19 Darmstadt, 64289 Germany.
- W. M. Haynes (ed) CRC Handbook of Chemistry and Physics, 94th Edition. CRC Press. Boca Roton, Florida, 2013; Section 4, Properties of the Elements and Organic Compounds: Magnetic susceptibility of the Elements and Organic Compounds; Section 12, Properties of Solids: Electrical Resistivity of Metals.
- [8] http://www.azom.com/article.aspx?ArticleID=965 10/03/15.
- [9] P. Goudket et al., Test Cavity for SRF Thin Film Evaluation, these proceedings.